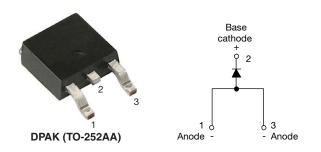


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Vishay Semiconductors

## High Voltage Surface Mountable Input Rectifier Diode, 8 A



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	8 A			
$V_{R}$	800 V, 1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.1 V			
I <sub>FSM</sub>	150 A			
T <sub>J</sub> max.	150 °C			
Package	DPAK (TO-252AA)			
Circuit configuration	Single			

#### **FEATURES**

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C







ROHS COMPLIANT HALOGEN FREE

#### **APPLICATIONS**

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

#### **DESCRIPTION**

The VS-8EWS..S-M3 rectifier high voltage series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

The **high reverse voltage** range available allows design of input stage primary rectification with **outstanding voltage surge** capability.

OUTPUT CURRENT IN TYPICAL APPLICATIONS			
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 μm) copper	1.2	1.6	
Aluminum IMS, R <sub>thCA</sub> = 15 °C/W	2.5	2.8	Α
Aluminum IMS with heatsink, R <sub>thCA</sub> = 5 °C/W	5.5	6.5	

#### Note

•  $T_A = 55 \,^{\circ}\text{C}$ ,  $T_J = 125 \,^{\circ}\text{C}$ , footprint 300 mm<sup>2</sup>

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I <sub>F(AV)</sub>	Sinusoidal waveform	8	А	
V <sub>RRM</sub>		800/1200	V	
I <sub>FSM</sub>		150	А	
V <sub>F</sub>	8 A, T <sub>J</sub> = 25 °C	1.10	V	
T <sub>J</sub>		-55 to +150	°C	

VOLTAGE RATINGS					
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA		
VS-8EWS08S-M3	800	900	0.5		
VS-8EWS12S-M3	1200	1300	0.5		



# VS-8EWS08S-M3, VS-8EWS12S-M3

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 105 °C, 180° conduction half sine wave	8	
Maximum peak one cycle		10 ms sine pulse, rated V <sub>RRM</sub> applied	125	А
non-repetitive surge current	10 ms sine pulse, no voltage reapplied	150		
Maximum I <sup>2</sup> t for fusing I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	78	A <sup>2</sup> s	
	1-1	10 ms sine pulse, no voltage reapplied	110	A-S
Maximum I²√t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	8 A, T <sub>J</sub> = 25 °C		1.1	V
Forward slope resistance	r <sub>t</sub>	- T <sub>J</sub> = 150 °C		20	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.82	V
Maximum rayaraa laakaga aurrant	1	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	0.05	mA
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 150 °C		0.50	IIIA

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> <sup>(1)</sup>		62	C/VV
Approximate weight			1	g
Approximate weight			0.03	oz.
Marking daying	Marking device	Case style DPAK (TO-252AA)	8EWS08S	
Marking device		Case style DFAR (10-252AA)	8EW	S12S

#### Note

<sup>(1)</sup> When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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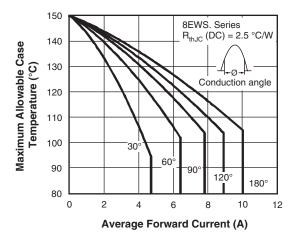


Fig. 1 - Current Rating Characteristics

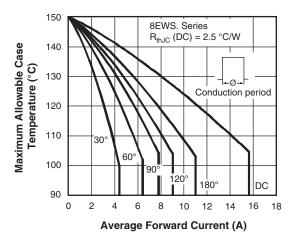


Fig. 2 - Current Rating Characteristics

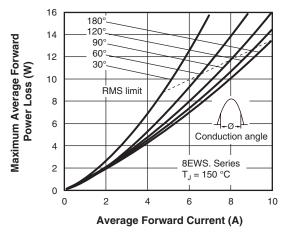


Fig. 3 - Forward Power Loss Characteristics

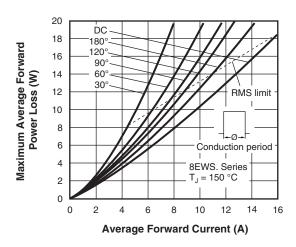


Fig. 4 - Forward Power Loss Characteristics

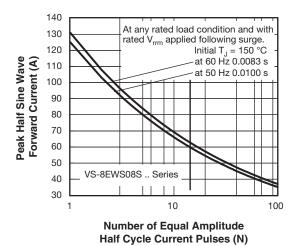


Fig. 5 - Maximum Non-Repetitive Surge Current

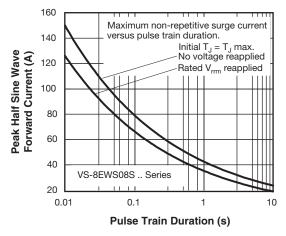
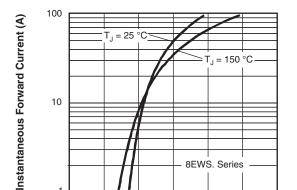


Fig. 6 - Maximum Non-Repetitive Surge Current

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1.0

0.5

0

1.5 Instantaneous Forward Voltage (V)

2.0

2.5

3.0

Fig. 7 - Forward Voltage Drop Characteristics

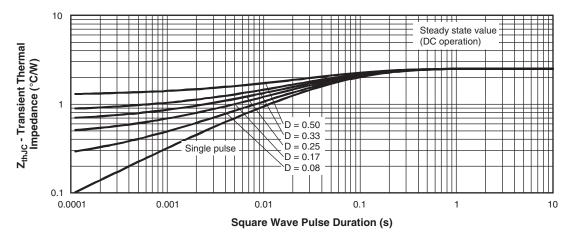
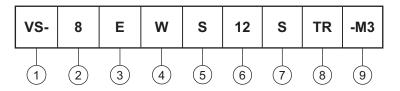


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

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#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

3 - Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage code x 100 = V<sub>RRM</sub> ---- 08 = 800 V 12 = 1200 V

7 - S = surface mountable

8 - • TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-8EWS08S-M3	75	3000	Antistatic plastic tubes	
VS-8EWS08STR-M3	2000	2000	13" diameter reel	
VS-8EWS08STRL-M3	3000	3000	13" diameter reel	
VS-8EWS08STRR-M3	3000	3000	13" diameter reel	
VS-8EWS12S-M3	75	3000	Antistatic plastic tubes	
VS-8EWS12STR-M3	2000	2000	13" diameter reel	
VS-8EWS12STRL-M3	3000	3000	13" diameter reel	
VS-8EWS12STRR-M3	3000	3000	13" diameter reel	

LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?95627</u>			
Part marking information	www.vishay.com/doc?95176		
Packaging information	www.vishay.com/doc?95033		
SPICE model	www.vishay.com/doc?96668		



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